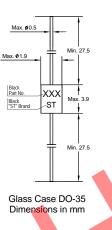
DB3, DB4, DC34

Silicon Bidirectional Trigger Diodes

These diacs are intended for use in thyristor phase control, circuits for lamp-dimming, universal-motor speed controls, and heat controls.



Absolute Maximum Ratings (T_a = 25 °C)

Parameter	Symbol	Value	Unit
Power Dissipation ($T_a = 65 \text{ °C}$)	P _{tot}	150	mW
Repetitive Peak On-state Current (tp = 20 µs, f = 100 Hz)	I _{TRM}	2	А
Operating Junction and Storage Temperature Range	T _j , T _{stg}	- 40 to + 125	°C

Characteristics at T_a = 25 °C

Parameter		Symbol	Min.	Max.	Unit
Breakover Voltage at C = 22 nF, see diagram 1	DB3	V _{BO}	28	36	V
	DC34		30	38	
	DB4		35	45	
Breakover Voltage Symmetry at C = 22 nF, see diagram 1		[+V _{BO} - -V _{BO}]	-	3	V
Dynamic Br <mark>ea</mark> kover Voltage at ∆I = [I _{BO} to I _F = 10 mA]		ΔV ±	5	-	V
Output Voltage See diagram 2		Vo	5	-	V
Breakover Current at C = 22 nF		I _{BO}	-	50	μA
Leakage Current at $V_B = 0.5 V_{BO}$ max		I _B	-	10	μA
Rise Time See diagram 3		t _r	-	2	μs

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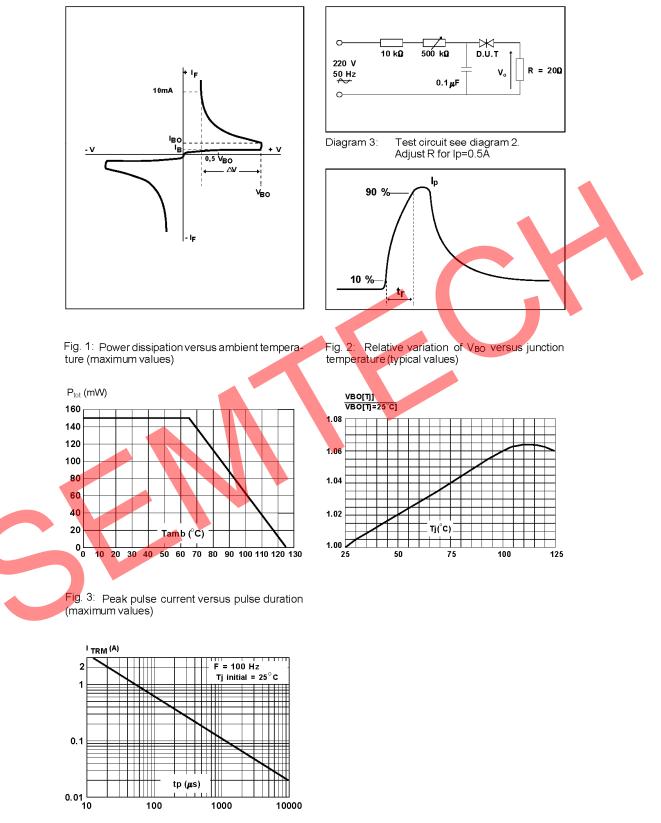


Diagram 1: Current-voltage characteristics

Diagram 2: Test circuit for output voltage





Dated : 08/08/2009

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